

# Phase Control Thyristors (Hockey PUK Version), 910 A



B-PUK (TO-200AC)

PRIMARY CHARACTERISTICS					
I <sub>T(AV)</sub> 910 A					
$V_{DRM}/V_{RRM}$	1200 V, 1600 V, 1800 V, 2000 V				
$V_{TM}$	1.80 V				
I <sub>GT</sub>	100 mA				
TJ	-40 °C to +125 °C				
Package	B-PUK (TO-200AC)				
Circuit configuration	Single SCR				

#### **FEATURES**

- · Center amplifying gate
- Metal case with ceramic insulator
- International standard case B-PUK (TO-200AC)



- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
		910	A			
I <sub>T(AV)</sub>	T <sub>hs</sub>	55	°C			
1		1857	A			
I <sub>T</sub> (RMS)	T <sub>hs</sub>	25	°C			
1	50 Hz	15 700	A			
ITSM	60 Hz	16 400	A			
I <sup>2</sup> t	50 Hz	1232	kA <sup>2</sup> s			
I-1	60 Hz	1125	KA-S			
$V_{DRM}/V_{RRM}$		1200 to 2000	V			
t <sub>q</sub>	Typical	150	μs			
$T_J$		-40 to 125	°C			

VOLTAGE F	VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM $MA$						
	12	1200	1300							
VS-ST700CL	16	1600	1700	80						
VS-31700CL	18	1800	1900	60						
	20	2000	2100							



ABSOLUTE MAXIMUM RATINGS	S					
PARAMETER	SYMBOL		VALUES	UNITS		
Maximum average on-state current	L	180° condu	180° conduction, half sine wave			Α
at heatsink temperature	$I_{T(AV)}$	double side	(single side) co	oled	55 (85)	°C
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 25 °C	heatsink temp	erature double side cooled	1857	
		t = 10 ms	No voltage		15 700	
Maximum peak, one-cycle	ı	t = 8.3 ms	reapplied		16 400	A kA <sup>2</sup> s
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		13 200	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	13 800	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 10 ms	No voltage reapplied	initial $T_J = T_J$ maximum	1232	
		t = 8.3 ms			1125	
		t = 10 ms	100 % V <sub>RRM</sub>		871	
	t = 8.3 ms reapplied			795		
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10	ms, no voltage	e reapplied	12 321	kA²√s
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$ ), $T_J = T_J$ maximum	1.00	V
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)})$	), $T_J = T_J$ maxin	1.13	v	
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x π	(16.7 % x $\pi$ x $I_{T(AV)}$ < I < $\pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum			mΩ
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.35	11152
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 2000 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.80	V
Maximum holding current	l <sub>Η</sub>	T 25 °C	· · · · · · · · · · · · · · · · · · ·			mA
Typical latching current	IL	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load			1000	IIIA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/μs
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	1.0	-16
Typical turn-off time	t <sub>q</sub>	$I_{TM}$ = 750 A, $T_J$ = $T_J$ maximum, dl/dt = 60 A/μs, $V_R$ = 50 V, dV/dt = 20 V/μs, gate 0 V 100 $\Omega$ , $t_p$ = 500 μs	150	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T <sub>J</sub> = T <sub>J</sub> maximum linear to 80 % rated V <sub>DRM</sub>	500	V/µs
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	80	mA



TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	
FANAMETEN	STIMBOL	I Ex	31 CONDITIONS	Тур.	Max.	UNITS
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \leq 5 \; ms$	10.0		W
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	f = 50  Hz, d% = 50	2	.0	\ \ \
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \leq 5 \; ms$	3	.0	Α
Maximum peak positive gate voltage	+V <sub>GM</sub>	T. – T. maximum	t < 5 ms	20		V
Maximum peak negative gate voltage	-V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms			5.0	
DC gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = -40 °C	Maximum required gate	200	-	
		T <sub>J</sub> = 25 °C		100	200	mA
		T <sub>J</sub> = 125 °C	trigger/	50	-	
		T <sub>J</sub> = -40 °C	current/voltage are the lowest value which will trigger all units	2.5	-	
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T <sub>J</sub> = 125 °C		1.1	-	
DC gate current not to trigger	I <sub>GD</sub>	$T_J = T_J \ maximum \\ maximum gate current/voltage \\ not to trigger is the maximum \\ value which will not trigger any \\ unit with rated V_{DRM} anode to \\ cathode applied$		1	0	mA
DC gate voltage not to trigger	$V_{GD}$			0.	25	٧

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	$T_J$		-40 to 125	- °C		
Maximum storage temperature range	T <sub>Stg</sub>		-40 to 150			
Maximum thermal resistance, junction to heatsink	р	DC operation single side cooled	0.073			
Maximum thermal resistance, junction to heatsink	R <sub>thJ-hs</sub>	DC operation double side cooled	0.031	K/W		
Marian and harmal and all and a large to the state of	R <sub>thC-hs</sub>	DC operation single side cooled	0.011	T√ VV		
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.006			
Mounting force, ± 10 %			14 700 (1500)	N (kg)		
Approximate weight			255	g		
Case style		See dimensions - link at the end of datasheet	B-PUK (TO-	200AC)		

△R <sub>thJ-hs</sub> CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST COMPITIONS	LIMITO
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum	
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		K/W
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

#### Note

• The table above shows the increment of thermal resistance RthJ-hs when devices operate at different conduction angles than DC

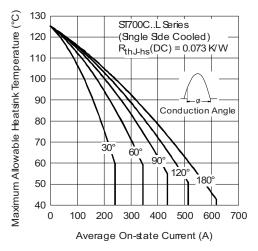


Fig. 1 - Current Ratings Characteristics

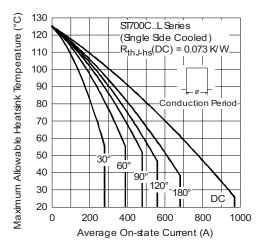


Fig. 2 - Current Ratings Characteristics

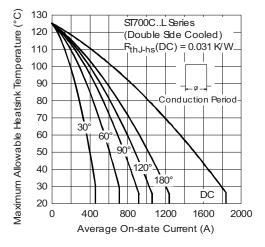


Fig. 3 - Current Ratings Characteristics

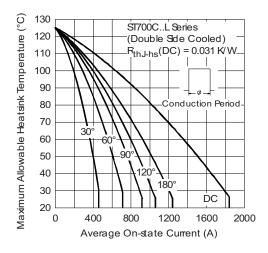


Fig. 4 - Current Ratings Characteristics

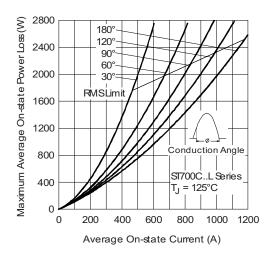


Fig. 5 - On-State Power Loss Characteristics

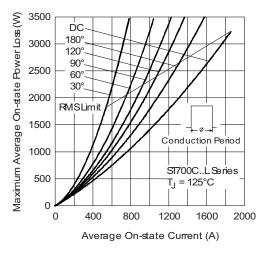


Fig. 6 - On-State Power Loss Characteristics

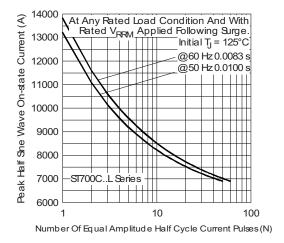


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

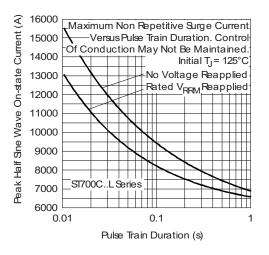


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

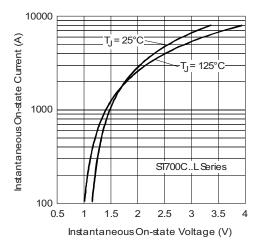


Fig. 9 - On-State Voltage Drop Characteristics

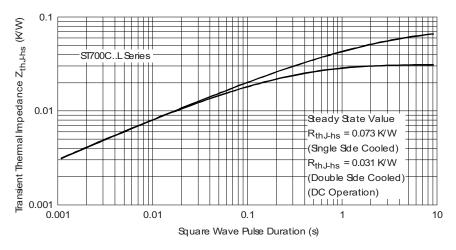


Fig. 10 - Thermal Impedance  $Z_{thJ\text{-}hs}$  Characteristics

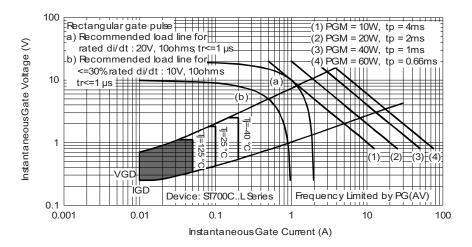
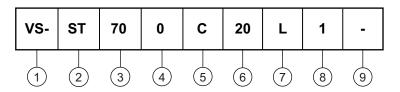


Fig. 11 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Thyristor

Essential part number

4 - 0 = converter grade

5 - C = ceramic PUK

6 - Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)

7 - L = PUK case B-PUK (TO-200AC)

8 - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = eyelet terminals (gate and auxiliary cathode soldered leads)

3 = fast-on terminals (gate and auxiliary cathode soldered leads)

9 - Critical dV/dt: • None = 500 V/μs (standard selection)

• L = 1000 V/µs (special selection)

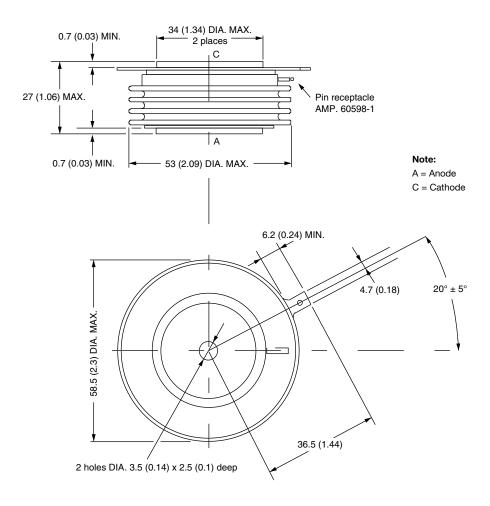
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95076			



# **B-PUK (TO-200AC)**

#### **DIMENSIONS** in millimeters (inches)

Creepage distance: 36.33 (1.430) minimum Strike distance: 17.43 (0.686) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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